

Flasher, 30-mΩ Shunt

Description

Bipolar integrated circuit, U643B, is used in relay-controlled automotive flashers where a high level EMC is required.

Lamp outage is indicated by frequency doubling during hazard warning as well as direction mode.

Features

- Temperature and supply voltage compensated flashing frequency
- Frequency doubling indicates lamp outage
- Relay driver output with high current carrying capacity and low saturation voltage
- Minimum lamp load for flasher operation: $\geq 1\text{ W}$
- Very low susceptibility to EMI
- Protection according to ISO/TR 7637/1 level 4

Ordering Information

Extended Type Number	Package	Remarks
U643B	DIP8	
U643B-FP	SO8	

Block Diagram

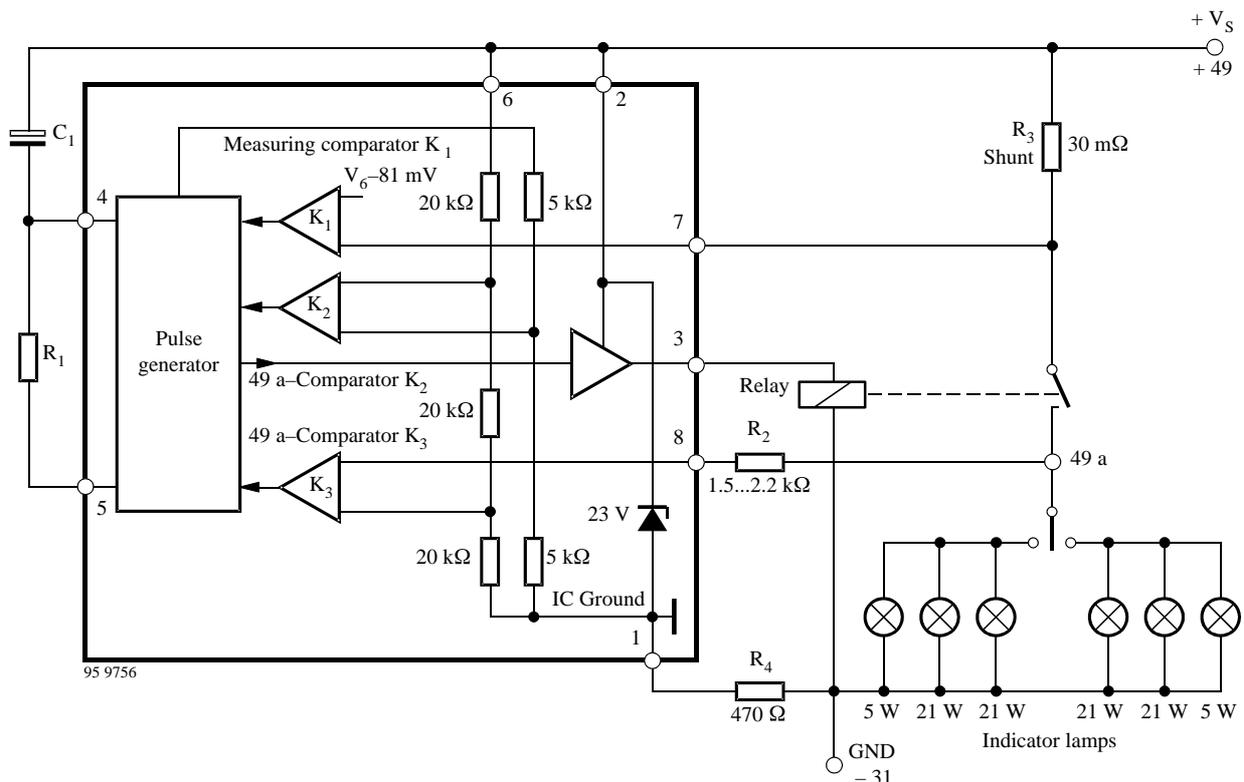


Figure 1. Application circuit as a car flasher
Resistor R₁, R₂ and R₄: 1/4 Watt
R₄ for protection against continuous reversed polarity: 0.5 Watt

Pin Description

Pin	Symbol	Function
1	GND	IC ground
2	V _S	Supply voltage V _S
3	REL	Relay driver
4	OSC	C ₁ Oscillator
5	OSC	R ₁ Oscillator
6	V _S	Supply voltage V _S
7	LD	Lamp failure detection
8	SI	Start input (49a)

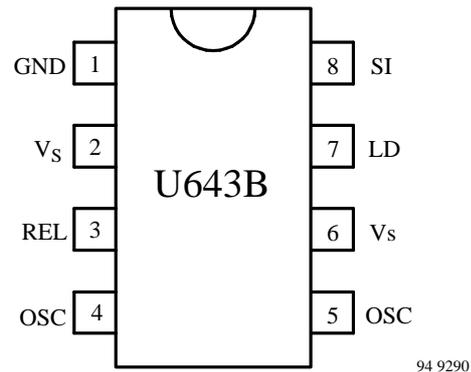


Figure 2. Pinning

Functional Description

Pin 1, GND

The integrated circuit is protected against damage via resistor R₄ to ground (–31) in the case of battery reversal. An integrated protection circuit together with external resistances R₂ and R₄ limits the current pulses in the IC.

Pin 2, Supply voltage, V_S - Power

The arrangement of the supply connections to Pin 2 must be such as ensure that, on the connection printed circuit board (PCB), the resistance of V_S to Pin 6 is lower than that to Pin 2.

Pin 3, Relay control output (driver)

The relay control output is a high-side driver with a low saturation voltage and capable to drive a typical automotive relay with a minimum coil resistance of 60 Ω.

Pin 4 and 5 Oscillator

Flashing frequency, f₁, is determined by the R₁C₁ components as follows (see figure 1):

$$f_1 \approx \frac{1}{R_1 \times C_1 \times 1.5} \text{ Hz}$$

where $C_1 \leq 47 \mu\text{F}$
 $R_1 = 6.8 \text{ k}\Omega \text{ to } 510 \text{ k}\Omega$

In the case of a lamp outage (see Pin 7) the oscillator frequency is switched to the lamp outage frequency f₂ with f₂ ≈ 2.2 × f₁.

Duty cycle in normal flashing mode: 50%
 Duty cycle in lamp outage mode: 40% (bright phase)

Pin 6, Supply voltage, Sense

For accurate monitoring via the shunt resistor, a mini-

mized layer resistance from point V_S / shunt to Pin 6 is recommended.

Pin 7, Lamp outage detection

The lamp current is monitored via an external shunt resistor R₃ and an internal comparator K1 with its reference voltage of typ. 81 mV (V_S = 12 V). The outage of one lamp out of two lamps is detected according to the following calculation:

Nominal current of 1 lamp: 21 W / (V_S = 12 V):

$$I_{\text{lamp}} = 1.75 \text{ A}$$

Nominal current of 2 lamps: 2 x 21 W / (V_S = 12 V):

$$I_{\text{lamp}} = 3.5 \text{ A}$$

The detection threshold is recommended to be set in the middle of the current range: I_{outage} ≈ 2.7 A

Thus the shunt resistor is calculated as:

$$R_3 = V_T (K1) / I_{\text{outage}}$$

$$R_3 = 81 \text{ mV} / 2.7 \text{ A} = 30 \text{ m}\Omega$$

Comparator K1's reference voltage is matched to the characteristics of filament lamps (see "control signal threshold" in the data part).

The combination of shunt resistor and resistance of wire harness prevents Pin 7 from a too high voltage in the case of shorted lamps.

Pin 8, Start input

Start condition for flashing: the voltage at Pin 8 has to be below K3 threshold (flasher switch closed).

Humidity and dirt may decrease the resistance between 49 a and GND. If this leakage resistance is > 5 kΩ the IC is still kept in its off-condition. In this case the voltage at Pin 8 is between the thresholds of comparators K2 and K3.

During the bright phase the voltage at Pin 8 is above the K2 threshold, during the dark phase it is below the K3 threshold. For proper start conditions a minimum lamp wattage of 1 W is required.

Absolute Maximum Ratings

Reference point Pin 1

Parameters	Symbol	Value	Unit
Supply voltage Pin 2 and 6	V_S	16.5	V
Surge forward current			
$t_p = 0.1$ ms Pin 2 and 6	I_{FSM}	1.5	A
$t_p = 300$ ms Pin 2 and 6	I_{FSM}	1.0	A
$t_p = 300$ ms Pin 8	I_{FSM}	50	mA
Output current Pin 3	I_O	0.3	A
Power dissipation			
$T_{amb} = 95^\circ\text{C}$ DIP 8	P_{tot}	420	mW
$T_{amb} = 95^\circ\text{C}$ SO 8	P_{tot}	340	mW
$T_{amb} = 60^\circ\text{C}$ DIP 8	P_{tot}	690	mW
$T_{amb} = 60^\circ\text{C}$ SO 8	P_{tot}	560	mW
Junction temperature	T_J	150	$^\circ\text{C}$
Ambient temperature range	T_{amb}	-40 ... +95	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 ... +150	$^\circ\text{C}$

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient DIP8	R_{thJA}	110	K/W
Junction ambient SO8	R_{thJA}	160	K/W

Electrical Characteristics

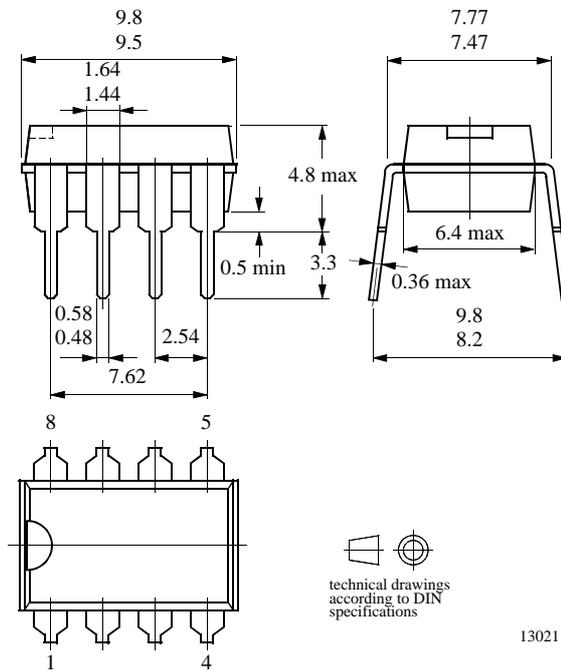
Typical values under normal operation in application circuit (see figure 1), V_S (+49, Pin 2 and 6) = 12 V.
Reference point ground (-31), $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply voltage range	Pin 2 and 6	V_S (+49)		9 to 15		V
Supply current:	Pin 2 and 6					
Dark phase		I_S		4.5	8	mA
Bright phase		I_S		7.0	11	mA
Relay output:	Pin 3					
saturation voltage	$I_O = 150$ mA, $V_S = 9$ V with resistance = 60 Ω	V_O			1.0	V
reverse current		I_O			0.1	mA
Start delay	First bright phase	t_{on}			10	ms
Frequency tolerance		δf_1	-5		+5	%
Bright period	Basic frequency f_1	Δf_1	47		53	%
	Control frequency f_2	Δf_2	37		45	%
Frequency increase	Lamp outage	f_2	2.15 f_1		2.3 f_1	Hz
Control signal threshold	$V_S = 15$ V Pin 7	V_{R3}	85	91	97	mV
	$V_S = 9$ V Pin 7	V_{R3}	66	71	76	mV
	$V_S = 12$ V Pin 7	V_{R3}	76	81	87	mV
Leakage resistance	49a to GND	R_p		4	5	k Ω
Lamp load		P_L	1			W

Package Information

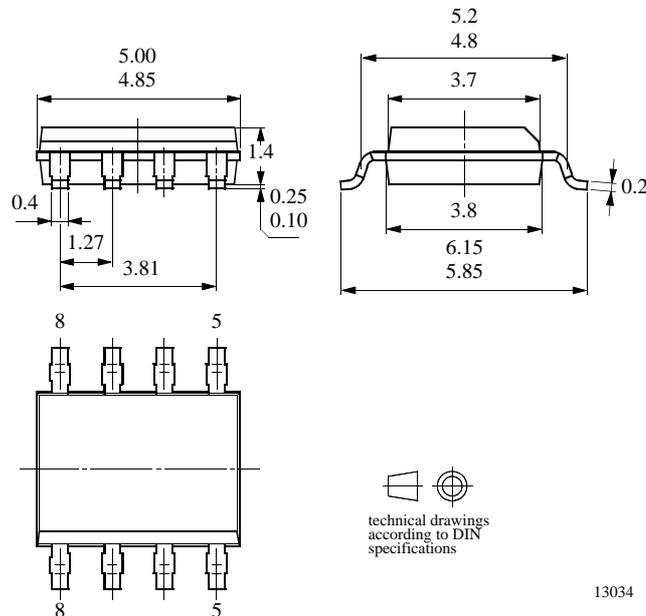
Package DIP8

Dimensions in mm



Package SO8

Dimensions in mm



Ozone Depleting Substances Policy Statement

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1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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